

FORM PTO-1449



Atty. Docket No.:
H0004667
(1139.1137101)

Serial No.:
10/612,660

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

Applicant: Bo Su Chen et al.

Filing Date:
July 2, 2003

Group Art:
unknown

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Examiner Initial	Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
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FORM PTO-1449

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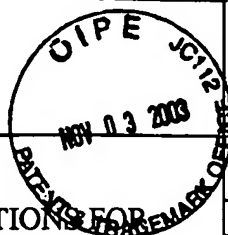
Group Art:

unknown



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FORM PTO-1449


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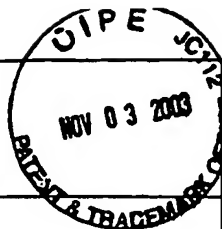
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FORM PTO-1449



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FORM PTO-1449



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✓	6,086,263	07/11/2000	Selli et al.			
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FORM PTO-1449



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MC	6,487,230	11/26/2002	Boucart et al.			

FORM PTO-1449


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MC	JP 02054981	02/23/1990	JP	Abstract
MC	JP 5299779	11/12/1993	JP	Abstract
MC	DE 4240706 A1	06/09/1994	DE	Abstract
MC	EP 0776076 A1	05/28/1997	EP	Abstract
MC	WO 98/57402	12/17/1998	PCT	

Page 8 of 13 FORM PTO-1449	Atty. Docket No.: H0004667 (1139.1137101)	Serial No.: 10/612,660
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	Applicant: Bo Su Chen et al.	
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MC	Choquette et al., "High Single Mode Operation from Hybrid Ion Implanted/Selectively Oxidized VCSELs", 200 IEEE 17th International Semiconductor Laser Conference, Monterrey, CA pages 59-60.
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Page 9 of 13	FORM PTO-1449 	Atty. Docket No.: H0004667 (1139.1137101)	Serial No.: 10/612,660
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Page 10 of 13 FORM PTO-1449	Atty. Docket No.: H0004667 (1139.1137101)	Serial No.: 10/612,660
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Page 11 of 13 FORM PTO-1449	Atty. Docket No.: H0004667 (1139.1137101)	Serial No.: 10/612,660
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EXAMINER: Michelle R. Connelly	DATE CONSIDERED: 2/22/06
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